

## Patent Assignment Abstract of Title

### Total Assignments: 1

**Application #:** 09928124

**Filing Dt:** 08/10/2001

**Patent #:** NONE

**Issue Dt:**

**PCT #:** NONE

**Publication #:** NONE

**Pub Dt:**

**Inventors:** John Snyder, John Larson

Fabrication method for a device for regulating flow of electric current with high

**Title:** dielectric constant gate insulating layer and source/drain forming schottky contact or schottky-like region with substrate

### Assignment: 1

**Reel/Frame:** 012074/0969

**Received:**  
08/20/2001

**Recorded:**  
08/10/2001

**Mailed:**  
10/19/2001

**Pages:** 4

**Conveyance:** ASSIGNMENT OF ASSIGNORS INTEREST (SEE DOCUMENT FOR DETAILS).

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**Exec Dt:** 08/10/2001

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Search Results as of: 1/28/2003 4:04:21 P.M.

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Web interface last modified: Oct. 5, 2002